SCES019N-JULY 1995-REVISED JULY 2004

#### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- Operates From 1.65 V to 3.6 V
- Max t<sub>pd</sub> of 5 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

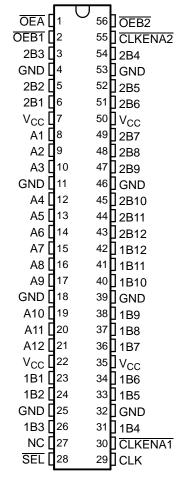
#### **DESCRIPTION/ORDERING INFORMATION**

This 12-bit to 24-bit registered bus exchanger is designed for 1.65-V to 3.6-V  $\rm V_{\rm CC}$  operation.

The SN74ALVCH16269 is used in applications in which two separate ports must be multiplexed onto, or demultiplexed from, a single port. The device is particularly suitable as an interface between synchronous DRAMs and high-speed microprocessors.

Data is stored in the internal B-port registers on the low-to-high transition of the clock (CLK) input when the appropriate clock-enable (CLKENA) inputs are low. Proper control of these inputs allows two sequential 12-bit words to be presented as a 24-bit word on the B port. For data transfer in the B-to-A direction, a single storage register is provided. The select (SEL) line selects 1B or 2B data for the A outputs. The register on the A output permits the fastest possible data transfer, extending the period during which the data is valid on the bus. The control terminals are registered so that all transactions are synchronous with CLK. Data flow is controlled by the active-low output enables (OEA, OEB1, OEB2).

# DGG OR DL PACKAGE (TOP VIEW)



NC - No internal connection

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	SSOP - DL	Tube	SN74ALVCH16269DL	ALVCH16269	
	330F - DL	Tape and reel	SN74ALVCH16269DLR		
-40°C to 85°C	TSSOP - DGG	Tape and reel	SN74ALVCH16269DGGR	ALVCH16269	
	VFBGA - GQL	Tana and root	SN74ALVCH16269KR	V/I IOCO	
	VFBGA - ZQL (Pb-free)	Tape and reel	74ALVCH16269ZQLR	VH269	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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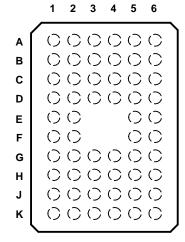


## **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

To ensure the high-impedance state during power up or power down, a clock pulse should be applied as soon as possible, and  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. Due to  $\overline{OE}$  being routed through a register, the active state of the outputs cannot be determined before the arrival of the first clock pulse.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

# GQL OR ZQL PACKAGE (TOP VIEW)



#### **TERMINAL ASSIGNMENTS**

	1	2	3	4	5	6
Α	2B3	OEB1	OEA	OEB2	CLKENA2	2B4
В	2B1	2B2	GND	GND	2B5	2B6
С	A2	A1	V <sub>CC</sub>	V <sub>CC</sub>	2B7	2B8
D	A4	А3	GND	GND	2B9	2B10
Е	A6	A5			2B11	2B12
F	A7	A8			1B11	1B12
G	A9	A10	GND	GND	1B9	1B10
Н	A11	A12	V <sub>CC</sub>	V <sub>CC</sub>	1B7	1B8
J	1B1	1B2	GND	GND	1B5	1B6
K	1B3	NC	SEL	CLK	CLKENA1	1B4



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### **FUNCTION TABLES**

#### **OUTPUT ENABLE**

I	NPUTS	3	OUTPUTS		
CLK OEA OEB		Α	1B, 2B		
1	Н	Н	Z	Z	
1	Н	L	Z	Active	
1	L	Н	Active	Z	
1	L	L	Active	Active	

# A-TO-B STORAGE ( $\overline{OEB} = L$ )

	INPUTS	OUTI	PUTS		
CLKENA1	<b>CLKENA2</b>	CLK	Α	1B	2B
L	Н	$\uparrow$	L	L	2B <sub>0</sub> <sup>(1)</sup>
L	Н	$\uparrow$	Н	Н	$2B_0^{(1)}$
L	L	$\uparrow$	L	L	L
L	L	$\uparrow$	Н	Н	Н
Н	L	$\uparrow$	L	1B <sub>0</sub> <sup>(1)</sup>	L
Н	L	$\uparrow$	Н	1B <sub>0</sub> <sup>(1)</sup>	Н
Н	Н	X	X	1B <sub>0</sub> <sup>(1)</sup>	$2B_0^{(1)}$

(1) Output level before the indicated steady-state input conditions were established

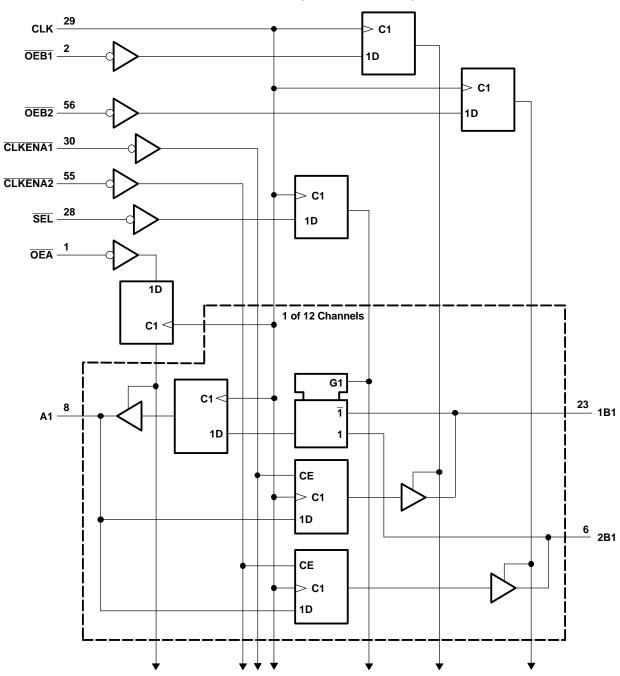
# B-TO-A STORAGE ( $\overline{OEA} = L$ )

	INPUTS							
CLK	SEL	1B	2B	Α				
Χ	Н	Χ	Χ	A <sub>0</sub> <sup>(1)</sup>				
Χ	L	Χ	Χ	$A_0^{(1)}$ $A_0^{(1)}$				
$\uparrow$	Н	L	Χ	L				
$\uparrow$	Н	Н	Χ	Н				
<b>↑</b>	L	Χ	L	L				
1	L	Χ	Н	Н				

(1) Output level before the indicated steady-state input conditions were established



## **LOGIC DIAGRAM (POSITIVE LOGIC)**



Pin numbers shown are for the DGG and DL packages.



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# ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
V	Input voltage range	Except I/O ports (2)	-0.5	4.6	V	
VI		I/O ports <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
Io	Continuous output current			±50	mA	
	Continuous current through each V <sub>CC</sub> or GN	ND		±100	mA	
		DGG package		81		
$\theta_{JA}$	Package thermal impedance (4)	DL package		74	°C/W	
		GQL/ZQL package		42		
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**

		·	MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		1.65	3.6	V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V <sub>CC</sub> = 1.65 V to 1.95 V	0	$.35 \times V_{CC}$		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8		
VI	Input voltage		0	$V_{CC}$	V	
Vo	Output voltage		0	$V_{CC}$	V	
		V <sub>CC</sub> = 1.65 V		-4		
	High lavel autout august	V <sub>CC</sub> = 2.3 V		-12	mA	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-12		
		V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
	Laur laurel austrust ausmant	V <sub>CC</sub> = 2.3 V	12		mA	
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V	•			
		V <sub>CC</sub> = 3 V		24		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

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### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
		I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2				
		I <sub>OH</sub> = -4 mA	1.65 V	1.2				
		I <sub>OH</sub> = -6 mA	2.3 V	2				
$V_{OH}$			2.3 V	1.7			V	
		I <sub>OH</sub> = -12 mA	2.7 V	2.2				
			3 V	2.4				
		I <sub>OH</sub> = -24 mA	3 V	2				
		I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V			0.2		
		I <sub>OL</sub> = 4 mA	1.65 V			0.45		
.,		I <sub>OL</sub> = 6 mA	2.3 V			0.4		
V <sub>OL</sub>		10 1	2.3 V			0.7	V	
		I <sub>OL</sub> = 12 mA	2.7 V			0.4		
		I <sub>OL</sub> = 24 mA	3 V			0.55		
I <sub>I</sub>		V <sub>I</sub> = V <sub>CC</sub> or GND	3.6 V			±5	μΑ	
		V <sub>I</sub> = 0.58 V	1.65 V	25				
		V <sub>I</sub> = 1.07 V	1.65 V	-25				
		V <sub>I</sub> = 0.7 V	2.3 V	45			μА	
I <sub>I(hold)</sub>		V <sub>I</sub> = 1.7 V	2.3 V	-45				
		V <sub>I</sub> = 0.8 V	3 V	75				
		V <sub>I</sub> = 2 V	3 V	-75				
		V <sub>I</sub> = 0 to 3.6 V <sup>(2)</sup>	3.6 V			±500		
I <sub>OZ</sub> (3)		$V_O = V_{CC}$ or GND	3.6 V			±10	μΑ	
I <sub>CC</sub>		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			40	μΑ	
$\Delta I_{CC}$		One input at $V_{CC}$ - 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 3.6 V			750	μΑ	
	Control inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		3.5		pF	
	A or B ports	$V_O = V_{CC}$ or GND	3.3 V		9		pF	

<sup>(1)</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to

<sup>(3)</sup> For I/O ports, the parameter  $I_{\mbox{\scriptsize OZ}}$  includes the input leakage current.



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### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			V <sub>CC</sub> = 1.8 V		$V_{CC}$ = 2.5 V $\pm$ 0.2 V		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			(1)		135		135		135	MHz
t <sub>w</sub>	Pulse duration, 0	CLK high or low	(1)		3.3		3.3		3.3		ns
		A data before CLK↑	(1)		2		2		1.7		
		B data before CLK↑	(1)		2.2		2.1		1.8		
t <sub>su</sub>	Setup time	SEL before CLK↑	(1)		1.6		1.6		1.3		ns
		CLKENA1 or CLKENA2 before CLK↑	(1)		1		1.2		0.9		
		OE before CLK↑	(1)		1.5		1.6		1.3		
		A data after CLK↑	(1)		0.7		0.6		0.6		
		B data after CLK↑	(1)		0.7		0.6		0.6		
t <sub>h</sub>	Hold time	SEL after CLK↑	(1)		1.1		0.7		0.7		ns
		CLKENA1 or CLKENA2 after CLK↑	(1)		1		0.8		1.1		
		OE after CLK↑	(1)		0.8		8.0		0.8		

<sup>(1)</sup> This information was not available at the time of publication.

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> =	: 1.8 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V V	V <sub>CC</sub> = 2	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V V	UNIT
		(OUTPUT)	MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			(1)		135		135		135		MHz
4	t <sub>nd</sub> CLK	В		(1)	1	8.2		7.3	1	6.2	20
t <sub>pd</sub>	CLK	Α		(1)	1	6.4		5.8	1	5	ns
	CLK	В		(1)	1	7.9		6.7	1	6.1	20
t <sub>en</sub>	CLK	А		(1)	1	7.6		6.2	1	5.9	ns
	CLIK	В		(1)	1	8.1		6.9	1	6.1	20
t <sub>dis</sub>	CLK	Α		(1)	1	7.5		6.8	1	5.6	ns

<sup>(1)</sup> This information was not available at the time of publication.

## **OPERATING CHARACTERISTICS**

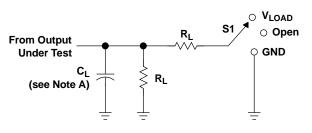
 $T_A = 25^{\circ}C$ 

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
_	Power dissipation	All outputs enabled	C 50 = 5 40 MH=	(1)	87	120	
$C_{pd}$	capacitance per exchanger	All outputs disabled	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	(1)	80.5	118	pF

<sup>(1)</sup> This information was not available at the time of publication.



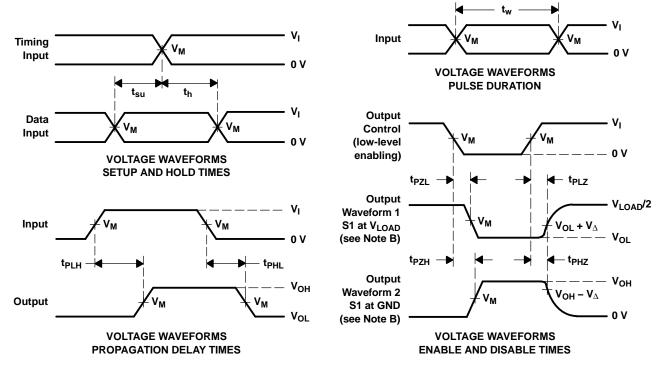
#### PARAMETER MEASUREMENT INFORMATION



TEST	<b>S</b> 1
t <sub>pd</sub> t <sub>PLZ</sub> /t <sub>PZL</sub> t <sub>PHZ</sub> /t <sub>PZH</sub>	Open V <sub>LOAD</sub> GND
1112 7211	

LOAD CIRCUIT

V	INPUT		V	v	•	В	, I
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	R <sub>L</sub>	$V_{\Delta}$
1.8 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O} = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





.com 25-Feb-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	n MSL Peak Temp <sup>(3)</sup>
74ALVCH16269ZQLR	ACTIVE	VFBGA	ZQL	56	1000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM
SN74ALVCH16269DGGR	ACTIVE	TSSOP	DGG	56	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
SN74ALVCH16269DL	ACTIVE	SSOP	DL	56	20	None	CU NIPDAU	Level-1-235C-UNLIM
SN74ALVCH16269DLR	ACTIVE	SSOP	DL	56	1000	None	CU NIPDAU	Level-1-235C-UNLIM
SN74ALVCH16269KR	ACTIVE	VFBGA	GQL	56	1000	None	SNPB	Level-1-240C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

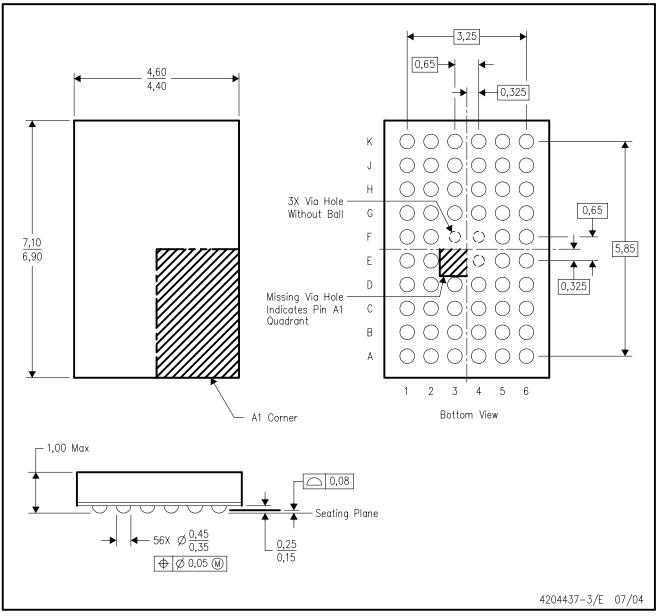
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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# ZQL (R-PBGA-N56)

# PLASTIC BALL GRID ARRAY



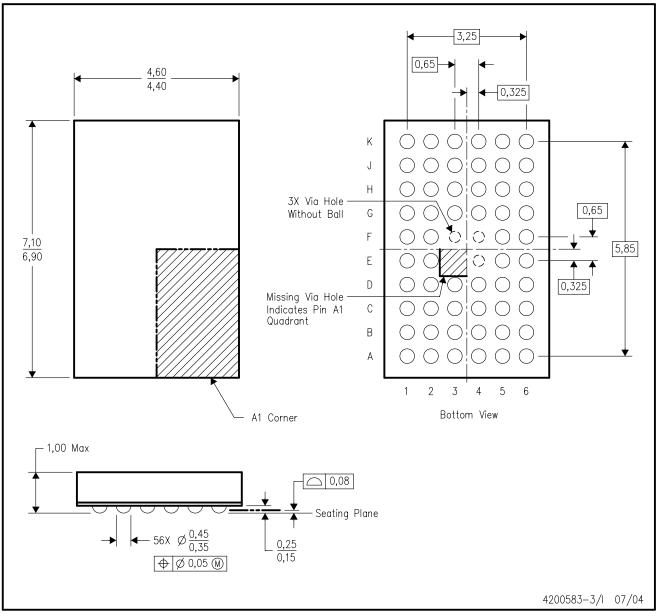
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



# GQL (R-PBGA-N56)

# PLASTIC BALL GRID ARRAY



NOTES:

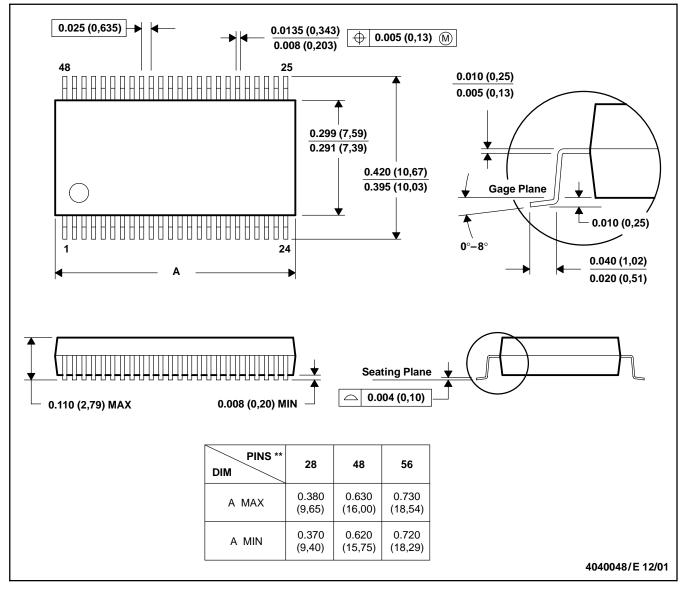
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



### DL (R-PDSO-G\*\*)

#### **48 PINS SHOWN**

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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